INTEGRATED CIRCUITS

DATA SHEET

FB2033

8-bit latched/registered/pass-thru Futurebus+ universal interface transceiver

Product specification

1995 May 25

IC19 data handbook

Philips Semiconductors



PHILIPS

FB2033

FEATURES

- 8-bit transceivers
- Latched, registered or straight through in either A to B or B to A path
- Drives heavily loaded backplanes with equivalent load impedances down to 10Ω.
- High drive 100mA BTL Open Collector drivers on B-port
- Allows incident wave switching in heavily loaded backplane buses
- Reduced BTL voltage swing produces less noise and reduces power consumption

- Built-in precision band-gap reference provides accurate receiver thresholds and improved noise immunity
- Compatible with IEEE Futurebus+ or proprietary BTL backplanes
- Each BTL driver has a dedicated Bus GND for a signal return
- Controlled output ramp and multiple GND pins minimize ground bounce
- Glitch-free power up/power down operation
- Low I_{CC} current
- Tight output skew
- Supports live insertion

QUICK REFERENCE DATA

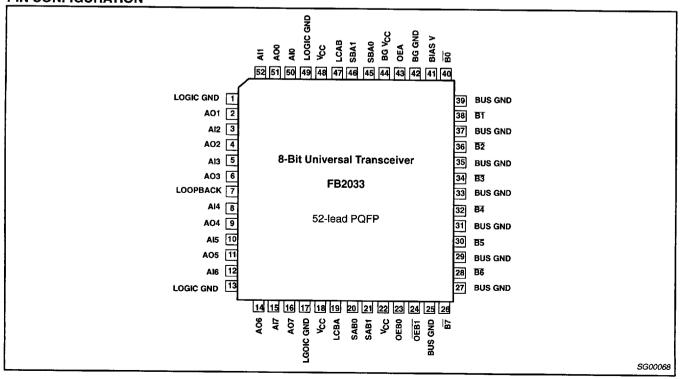
SYMBOL	P/	ARAMETER	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay Aln to Bn		3.0 3.0	ns
t _{PLH} t _{PHL}	Propagation delay Bn to AOn		4.3 4.1	ns
C _{OB}	Output capacitance (B0	– Bn only)	6	pF
loL	Output current (B0 - Bn	only)	100	mA
1.	Constant	Aln to Bn (outputs Low or High)	24	
lcc	Supply current	Bn to AOn (outputs Low)	45	mA
	Bn to AOn (outputs High)		22	

ORDERING INFORMATION

PACKAGES	COMMERCIAL RANGE V _{CC} = 5V±10%; T _{amb} = 0°C to +70°C	DRAWING NUMBER
52-pin Plastic Quad Flat Pack (QFP)	FB2033BB	SOT379-1
NOTE: The second		

NOTE: Thermal mounting or forced air is recommended

PIN CONFIGURATION



FB2033

DESCRIPTION

The FB2033 is an 8-bit transceiver featuring a split input (AI) and output (AO) bus on the TTL-level side.

The common I/O, open collector B port operates at BTL signal levels. The logic element for data flow in each direction is controlled by two pairs of mode select inputs (SBA0 and SBA1 for B-to-A, SAB0 and SAB1 for A-to-B). It can be configured as a buffer, a register, or a D-type latch.

When configured in the buffer mode, the inverse of the input data appears at the output port. In the flip-flop mode, data is stored on the rising edge of the appropriate clock input (LCAB or LCBA). In the latch mode, clock pins serve as transparent-High latch enables. Regardless of the mode, data is inverted from input to output.

Data flow in the B-to-A direction, regardless of the logic element selected, is further controlled by the Loopback input. When the Loopback input is High the output of the selected A-to-B logic element (not inverted) becomes the B-to-A input.

The 3-State AO port is enabled by asserting a High level on OEA. The B port has two output enables, OEB0 and OEBT. Only when OEB0 is High and OEBT is Low is the output enabled. When either OEB0 Is Low or OEBT is High, the B-port is inactive and is pulled to the level of the pull-up voltage. New data can be entered in the flip-flop and latched modes or can be retained while the associated outputs are in 3-State (AO port) or inactive (B port).

The B-port drivers are Low-capacitance open collectors with controlled ramp and are designed to sink 100mA. Precision band gap references on the B-port ensure very good noise margins by limiting the switching threshold to a narrow region centered at 1.55V.

The B-port interfaces to "Backplane Transceiver Logic" (see the IEEE 1194.1 BTL standard). BTL features low power consumption

by reducing voltage swing (1V p-p, between 1V and 2V) and reduced capacitive loading by placing an internal series diode on the drivers. BTL also provides incident wave switching, a necessity for high performance backplanes.

Output clamps are provided on the BTL outputs to further reduce switching noise. The " V_{OH} " clamp reduces inductive ringing effects during a Low-to-High transition. The " V_{OH} " clamp is always active. The other clamp, the "trapped reflection" clamp, clamps out ringing below the BTL 0.5V V_{OL} level. This clamp remains active for approximately 100ns after a High-to-Low transition.

To support live insertion, OEB0 is held Low during power on/off cycles to ensure glitch- free B port drivers. Proper bias for B port drivers during live insertion is provided by the BIAS V pin when at a 5V level while V_{CC} is Low. The BIAS V pin is a low current input which will reverse-bias the BTL driver series Schottky diode, and also bias the B port output pins to a voltage between 1.62V and 2.1V. This bias function is in accordance with IEEE BTL Standard 1194.1. If live insertion is not a requirement, the BIAS V pin should be tied to a V_{CC} pin.

The LOGIC GND and BUS GND pins are isolated inside the package to minimize noise coupling between the BTL and TTL sides. These pins should be tied to a common ground external to the package.

Each BTL driver has an associated BUS GND pin that acts as a signal return path and these BUS GND pins are internally isolated from each other. In the event of a ground return fault, a "hard" signal failure occurs instead of a pattern dependent error that may be very infrequent and impossible to trouble- shoot.

As with any high power device thermal considerations are critical. It is recommended that airflow (300lfpm) and/or thermal mounting be used to ensure proper junction temperature.

PIN DESCRIPTION

SYMBOL	PIN NUMBER	TYPE	NAME AND FUNCTION
Al0 – Al7	50, 52, 3, 5, 8, 10, 12, 15	Input	Data inputs (TTL)
AO0 – AO7	51, 2, 4, 6, 9, 11, 14, 16	Output	3-State outputs (TTL)
B0 – B7	40, 38, 36, 34, 32, 30, 28, 26	1/0	Data inputs/Open Collector outputs, High current drive (BTL)
OEB0	23	Input	Enables the B outputs when High
OEB1	24	Input	Enables the B outputs when Low
OEA	43	Input	Enables the AO outputs when High
BUS GND	39, 37, 35, 33, 31, 29, 27, 25	GND	Bus ground (0V)
LOGIC GND	1, 13, 17, 49	GND	Logic ground (0V)
V _{CC}	18, 22, 48	Power	Positive supply voltage
BIAS V	41	Power	Live insertion pre-bias pin
BG V _{CC}	44	Power	Band Gap threshold voltage reference
BG GND	42	GND	Band Gap threshold voltage reference ground
SABn	20, 21	Input	Mode select from AI to B
SBAn	45, 46	Input	Mode select from B to AO
LCAB	47	Input	A-to-B clock/latch enable (transparent latch when High)
LCBA	19	Input	B-to-A clock/latch enable (transparent latch when High)
Loopback	7	Input	Enables loopback function when High (from Aln to AOn)

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FUNCTION TABLE

					INPUTS	3				ООТ	PUTS
MODE	Aln	Bn*	OEB0	OEB1	OEA	LCAB	LCBA	SAB ₁	SBA ₁	AOn	Bn
Aln to Bn thru mode	L	_	Н	L	L	Х	Х	LL	XX	Z	H**
The branch mode	н		Н	L	L	х	×	LL.	XX	Z	L
Ain to Bn transparent latch	L	_	Н	L	L	Н	Х	НХ	XX	Z	H**
7 th to 57 handparent later	Н	-	Н	L	L	Н	Х	нх	XX	z	L
Aln to Bn latch and read	1	-	Н	L	L	↓	Х	НХ	XX	z	H**
Tan to Sit fatori and Toda	h		Н	L	L	1	Х	нх	XX	Z	L
Aln to Bn register	L		Н	L	L	1	Х	LH	XX	Z	H**
	Н	_	Н	L	L	1	Х	LH	XX	Z	L
Bn outputs latched and read (preconditioned latch)	х	_	Н	L	L	L	х	нх	xx	Z	latched data
Bn to AOn thru mode	Х	L	L	Н	Н	Х	Х	XX	LL	Н	input
The state of the s	Х	Н	L	Η	ı	Х	Х	XX	LL	L	input
Bn to AOn transparent latch	Х	L	L	H	I	х	Н	XX	НХ	Н	input
- Sit to North Garloparent later	Х	Н	L	Н	Н	Х	Н	XX	НХ	L	input
Bn to AOn latch and read	Х	ı	L	H	Н	Х	↓	XX	НХ	Н	input
Direction atomana road	Х	h	L	Ξ	Н	Х	1	XX	НХ	L	input
Bn to AOn register	Х	L	L	Ι	Н	Х	1	XX	LH	Н	input
	Х	Η	L	Н	Н	Х	1	XX	LH	L	input
AOn outputs latched and read (preconditioned latch)	х	Х	L	Н	Н	х	L	XX	НХ	latched data	х
Disable Bn outputs	Х	Х	L	Х	Х	Х	Х	XX	XX	Х	H**
	Х	Х	Х	Н	Х	Х	Х	XX	XX	Х	H**
Disable AOn outputs	Х	Х	Х	Х	L	Х	Х	XX	XX	Z	X

FUNCTION SELECT TABLE

MODE SELECTED	SXX1	SXX0
Thru mode	L	L
Register mode	L	Н
Latch mode	Н	X

NOTES:

H = High voltage level

L = Low voltage level

h = High voltage level one set-up time prior to the High-to-Low LCXX transition

I = Low voltage level one set-up time prior to the High-to-Low LCXX transition

X = Don't care

Z = High-impedance (OFF) state

— = Input not externally driven

↑ = Low-to-High transition

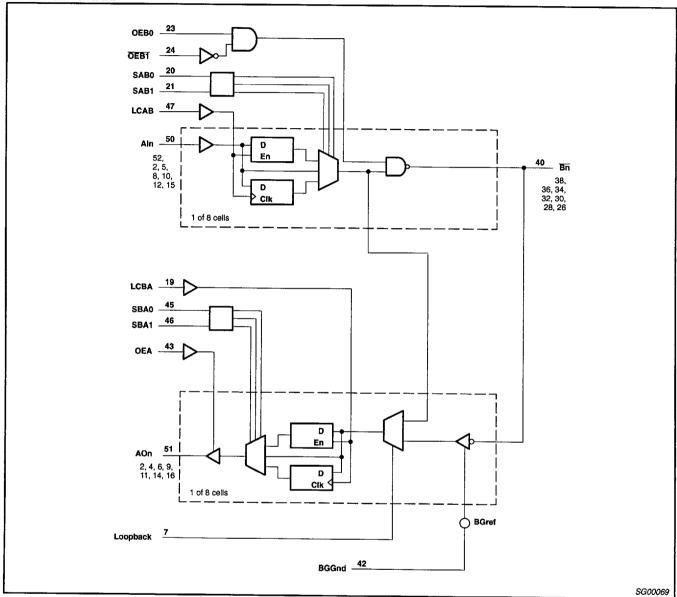
High-to-Low transition

H** = Goes to level of pull-up voltage

Bn* = Precaution should be taken to ensure B inputs do not float. If they do, they are equal to Low state.

NOTE: In Loopback mode (Loopback = High), Aln inputs are routed to the AOn outputs. The Bn inputs are blocked out.

LOGIC DIAGRAM



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ABSOLUTE MAXIMUM RATINGS
Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.

SYMBOL	PARAMETE	R	RATING	UNIT	
V _{CC}	Supply voltage		-0.5 to +7.0	V	
V _{IN}	Input voltage	All inputs except B0 - Bn	-1.2 to +7.0	T	
* IIN	The voltage	B0 – Bn	-1.2 to +3.5	 	
I _{IN}	Input current		-40 to +5.0	mA	
V _{OUT}	Voltage applied to output in High output state		-0.5 to +V _{CC}	V	
lout	Current applied to output in Low output state	AO0 – AOn	48	1	
1001	Current applied to output in Low output state	B0 – Bn	200	d mA	
T _{STG}	Storage temperature		-65 to +150	°C	

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAME	TED	•			
	PARAME	IEN	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		4.5	5.0	5.5	V
V _{IH}	High-level input voltage	Except BO – Bn	2.0		· · · · · · · · · · · · · · · · · · ·	
▼IH	Tilgilleveriliput voltage	B0 – Bn	1.62	1.55		V
V _{IL}	Low-level input voltage	Except BO – Bn			0.8	٧
* IL	20W level input voltage	B0 – Bn			1.47	
luz	Input clamp current	Except BO – Bn	-		-40	mA
ŀК		BO – Bn			-50	
¹ он	High-level output current	AO0 – AOn			-3	mA
loL	Low-level output current	AO0 – AOn			24	
·OL	Low-level output current	B0 – Bn			100	mA
I _{IA}	Off device input current	Except BO - Bn, V _I = 0 to 5.5V, V _{CC} = 0V			100	μА
СОВ	Output capacitance of B port			6	7	pF
Tamb	Operating free-air temperature range		0		+70	- -

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating free-air temperature range unless otherwise noted.

SYMBOL	PARAMETER		TEST CONDITIONS ¹				
	TANAMETE		TEST CONDITIONS.	MIN	TYP ²	MAX	UNI.
Юн	High level output current	B0 – Bn	$V_{CC} = MAX$, $V_{IL} = MAX$, $V_{IH} = MIN$, $V_{OH} = 1.9V$			100	μА
l _{OFF}	Power-off output current	B0 – Bn	$V_{CC} = 0.0V$, $V_{IL} = MAX$, $V_{IH} = MIN$, $V_{OH} = 1.9V$			100	μA
V _{OH}	High-level output voltage	AO0 – AOn ⁴	V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN, I _{OH} = -3mA	2.5	2.85		V
		AO0 – AOn ⁴	V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN, I _{OL} = 24mA			0.5	
V_{OL}	Low-level output voltage	B0 – Bn	V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN, I _{OL} = 100mA	.75	1.0	1.15	v
	$V_{CC} = MIN, V_{IL} = MAX, V_{IH}$		V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN, I _{OL} = 4mA	0.5			1
		Except B0-Bn	V _{CC} = MIN, I _I = I _{IK}			-0.5	
V_{IK}	Input clamp voltage	B0 - Bn	V _{CC} = MIN, I _I = I _{IK} ⁶	0.3			٧
		B0 - Bn	V _{CC} = MIN, I _I = -18mA			-1.2	1
l _l	Input current at maximum input voltage	Except B0-Bn	V _{CC} = MAX, V _I = 0.0V or 5.5V			±50	μА
		Except B0-Bn	$V_{CC} = MAX$, $V_1 = 2.7V$, $\overline{Bn} = Aln = 0V$			20	μА
I _{IH}	High-level input current	B0 – Bn	V _{CC} = MAX, V _I = 1.9V			100	"
		BU = BII	V _{CC} = MAX, V _I = 3.5V ⁵	100			mA
I _{IL}	Low-level input current	Except B0-Bn	V _{CC} = MAX, V _I = 0.5V			-20	μА
		B0 – Bn	V _{CC} = MAX, V _I = 0.75V			-100	μ
lozн	Off-state output current	AO0 – AOn	$V_{CC} = MAX, V_O = 2.7V$			50	μА
lozL	Off-state output current	AO0 – AOn	$V_{CC} = MAX, V_O = 0.5V$			-50	μA
los	Short-circuit output current ³	AO0 – AOn only	$V_{CC} = MAX, V_O = 0.0V$	-45		-150	mA
		Aln to Bn	V _{CC} = MAX, outputs Low or High		24	50	
Icc	Supply current (total)	Bn to AOn	V _{CC} = MAX, outputs Low		45	75	mA
		Bn to AOn	V _{CC} = MAX, outputs High		22	44	

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operation conditions for the applicable type.
 All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
 Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, IOS tests should be performed last.
- Sequence of parameter lests, for lests should be performed last.
 Due to test equipment limitations, actual test conditions are V_{IH} = 1.8V and V_{IL} = 1.3V for the B side.
 For B port input voltage between 3 and 5 volts I_{IH} will be greater than 100μA, but the parts will continue to function normally.
 BO B7 clamps remain active for a minimum of 80ns following a High-to-Low transition.

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LIVE INSERTION SPECIFICATIONS

SYMBOL	j	PARAMETER		LIMITS		
			MIN	NOM	MAX	UNIT
V _{BIASV}	Bias pin voltage	V _{CC} = 0 to 5.25V, Bn = 0 to 2.0V	4.5		5.5	V
BIASV	Bias pin DC current	V _{CC} = 0 to 4.75V, Bn = 0 to 2.0V, Bias V = 4.5 to 5.5V	"		1	mA
	Blas pin Bo carrent	V _{CC} = 4.5 to 5.5V, Bn = 0 to 2.0V, Bias V = 4.5 to 5.5V			10	μА
V_{Bn}	Bus voltage during pre-bias	BO - BB = 0V, Bias $V = 5.0V$	1.62		2.1	V
I _{LM}	Fall current during pre-bias	$\overline{B0} - \overline{B8} = 2V$, Bias $V = 4.5$ to 5.5V	1			μА
I _{HM}	Rise current during pre-bias	$\overline{B0} - \overline{B8} = 1V$, Bias $V = 4.5$ to 5.5V	-1			μА
I Bn PEAK	Peak bus current during insertion	$V_{CC} = 0$ to 5.25V, $\overline{B0} - \overline{B8} = 0$ to 2.0V, Bias V = 4.5 to 5.5V, OEB0 = 0.8V, $t_r = 2$ ns			10	mA
IOLOFF	Power up current	V _{CC} = 0 to 5.25V, OEB0 = 0.8V			100	
OLUFF	i ower up current	V _{CC} = 0 to 2.2V, OEB0 = 0 to 5V			100	μA
t _{GR}	Input glitch rejection	V _{CC} = 5.0V	1.0	1.35		ns

AC ELECTRICAL CHARACTERISTICS

					A PORT I	IMITS		
SYMBOL	PARAMETER	TEST CONDITION	T_{amb} = +25°C, V_{CC} = 5V, C_L = 50pF, R_L = 500 Ω			T _{amb} = 0 V _{CC} = 5 C _L = 50pF,	UNIT	
			MIN	TYP	MAX	MIN	MAX	1
f _{MAX}	Maximum clock frequency	Waveform 4	100	150		100		MHz
t _{PLH} t _{PHL}	Propagation delay (thru mode) Bn to AOn	Waveform 1, 2	2.2 2.0	4.3 4.1	6.0 6.0	2.0 1.8	7.0 7.0	ns
t _{PLH} t _{PHL}	Propagation delay (transparent latch) Bn to AOn	Waveform 1, 2	1.5 2.4	4.5 4.4	6.5 6.5	1.0 2.0	7.5 7.5	ns
t _{PLH} t _{PHL}	Propagation delay LCBA to AOn	Waveform 1, 2	2.0 2.2	3.8 4.3	5.5 6.0	1.8 1.7	6.0 6.5	ns
t _{PLH} t _{PHL}	Propagation delay SBAn to AOn	Waveform 1, 2	1.4 1.4	2.9 3.1	5.0 5.5	1.0	6.0 6.5	ns
t _{PLH} t _{PHL}	Propagation delay (Loopback mode) Aln to AOn	Waveform 1, 2	2.0 2.0	3.8 3.9	6.0 6.0	2.8 2.3	7.0 7.0	ns
t _{PLH} t _{PHL}	Propagation delay (Loopback mode) Loopback to AOn	Waveform 1, 2	1.2 1.2	3.4 3.2	5.0 5.5	1.0	6.0 6.5	ns
t _{PZH} t _{PZL}	Output enable time from High or Low OEA to AOn	Waveform 5, 6	1.0 2.6	3.1 4.0	5.1 5.5	1.0 2.4	5.5 5.8	ns
t _{PHZ} t _{PLZ}	Output disable time to High or Low OEA to AOn	Waveform 5, 6	1.0 1.0	3.5 3.3	5.0 4.6	1.7 1.7	5.6 5.2	ns
t _{TLH} t _{THL}	Output transition time, AOn Port 10% to 90%, 90% to 10%	Test Circuit and Waveforms				2.0	5.0 5.0	ns
t _{SK} (o)	Output to output skew, A port 1	Waveform 3		0.5	1.0		1.5	ns
t _{SK} (p)	Pulse skew 2 t _{PHL} - t _{PLH} MAX	Waveform 2		0.3	1.0	-	1.5	ns

NOTES:

Bn to AOn propagation delays are extended for 5 nanoseconds following B port excursions above 3.1 volts.
 İthactual – İthactual | for any data input to output path compared to any other data input to output path where N and M are either LH or HL. Skew times are valid only under same test conditions (temperature, V_{CC}, loading, etc.).
 İtak(p) is used to quantify duty cycle characteristics. In essence it compares the input signal duty cycle to the corresponding output signal duty cycle (50MHz input frequency and 50% duty cycle, tested on data paths only).

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AC ELECTRICAL CHARACTERISTICS (Continued)

					B PORT	LIMITS		
SYMBOL	PARAMETER	TEST CONDITION	T _{amb} = +25°C, V _{CC} = 5V, C _D = 30pF, R _U = 9Ω			$T_{amb} = 0$ to 70° C, $V_{CC} = 5V \pm 10\%$, $C_D = 30$ pF, $R_U = 9\Omega$		UNIT
			MIN	ТҮР	MAX	MIN	MAX]
t _{PLH} t _{PHL}	Propagation delay (thru mode) Aln to Bn	Waveform 1, 2	1.2 1.0	2.9 2.9	4.3 4.4	1.0 1.0	4.8 4.6	ns
t _{PLH} t _{PHL}	Propagation delay (transparent latch) Aln to Bn	Waveform 1, 2	1.4 1.0	3.1 3.3	4.5 4.8	1.0 1.0	5.1 5.1	ns
t _{PLH} t _{PHL}	Propagation delay LCAB to Bn	Waveform 1, 2	2.7 2.2	4.4 5.1	5.7 6.6	2.4 2.0	6.4 7.1	ns
t _{PLH} t _{PHL}	Propagation delay SABn to Bn	Waveform 1, 2	1.8 1.0	3.6 3.3	5.0 4.9	1.4 1.0	5.7 5.2	ns
t _{PZH} t _{PZL}	Enable/disable time OEB0 or OEB1 to Bn	Waveform 1, 2	1.4 1.0	3.0 3.1	4.5 5.0	1.0 1.0	5.0 5.6	ns
ΔV/Δt	Output transition rate, Bn Port 20% to 80%, 80% to 20%	Test Circuit and Waveforms				0.4	1.2	V/ns
t _{SK} (o)	Output to output skew, B port ¹	Waveform 3		0.8	1.5		2.0	ns
t _{SK} (p)	Pulse skew 2 t _{PHL} - t _{PLH} _{MAX}	Waveform 2		0.3	1.5			ns
SYMBOL	PARAMETER	TEST CONDITION	F	t _U = 16.59		R _U =	UNIT	
t _{PLH} t _{PHL}	Propagation delay (thru mode) Aln to Bn	Waveform 1, 2	1.2 1.0	3.0 3.0	4.4 4.5	1.0 1.0	4.9 4.7	ns
t _{PLH} t _{PHL}	Propagation delay (transparent latch) Aln to Bn	Waveform 1, 2	1.4 1.0	3.2 3.4	4.6 4.9	1.0 1.0	5.2 5.2	ns
t _{PLH} t _{PHL}	Propagation delay LCAB to Bn	Waveform 1, 2	2.7 2.2	4.5 5.2	5.8 6.7	2.4 2.0	6.5 7.2	ns
t _{PLH} t _{PHL}	Propagation delay SABn to Bn	Waveform 1, 2	1.8 1.0	3.7 3.4	5.1 5.0	1.4 1.0	5.8 5.3	ns
t _{PZH} t _{PZL}	Enable/disable time OEB0 or OEB1 to Bn	Waveform 1, 2	1.4 1.0	3.1 3.2	4.6 5.1	1.0 1.0	5.1 5.7	ns
ΔV/Δt	Output transition rate, Bn Port 20% to 80%, 80% to 20%	Test Circuit and Waveforms				0.2	0.6	V/ns
t _{SK} (o)	Output to output skew, B port ¹	Waveform 3		0.5	1.0		1.5	ns
t _{SK} (p)	Pulse skew ² t _{PHL} - t _{PLH} _{MAX}	Waveform 2		0.3	1.0		1.5	ns

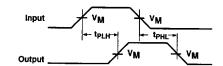
Itanactual – tpMactual | for any data input to output path compared to any other data input to output path where N and M are either LH or HL. Skew times are valid only under same test conditions (temperature, V_{CC}, loading, etc.).
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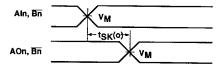
AC SETUP REQUIREMENTS

					LIMI	TS		
SYMBOL	PARAMETER	TEST	T _{amb} =	+25°C, V	_{CC} = 5V	T _{amb} = 0 to 70°C, V _{CC} = 5V±10%		UNIT
		CONDITION	C _L	= 50pF (L = 500Ω	A side) / (A side) /	C _D = 30pF (E ' R _U = 9Ω (B	3 side) side)	JUNII
			MIN	TYP	MAX	MIN	MAX	7
t _s (H) t _s (L)	Setup time Aln to LCAB or Bn to LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns
t _h (H) t _h (L)	Hold time Aln to LCAB or Bn to LCBA	Waveform 4	1.0 1.0			1.3 1.3		ns
t _w (H) t _w (L)	Pulse width, High or Low LCAB or LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns
SYMBOL	PARAMETER	TEST CONDITION	C _L	= 50pF (= 500Ω (/	A side) / (A side) /	C _D = 30pF (E R _U = 16.5Ω (side) B side)	UNIT
t _s (H) t _s (L)	Setup time Aln to LCAB or Bn to LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns
t _h (H) t _h (L)	Hold time Aln to LCAB or Bn to LCBA	Waveform 4	1.0 1.0			1.3 1.3		ns
t _w (H) t _w (L)	Pulse width, High or Low LCAB or LCBA	Waveform 4	3.0 3.0			4.0 4.0		ns

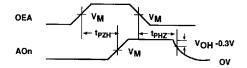
AC WAVEFORMS



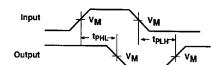
Waveform 1. Propagation Delay for Data or Output Enable to Output



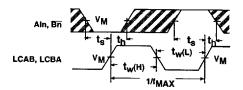
Waveform 3. Output to Output Skew



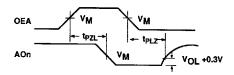
Waveform 5. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 2. Propagation Delay for Data or Output Enable to Output



Waveform 4. Setup and Hold Times, Pulse Widths and Maximum Frequency



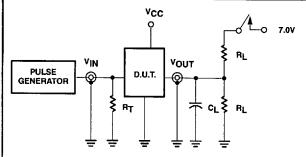
Waveform 6. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

NOTE: The shaded areas indicate when the input is permitted to change for predictable output performance.

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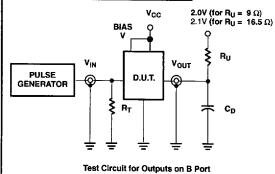
TEST CIRCUIT AND WAVEFORMS



Test Circuit for 3-State Outputs on A Port

SWITCH POSITION

TEST	SWITCH
t _{PLZ,} t _{PZL}	closed
All other	open



NEGATIVE PULSE	90% t _W 10% t _{THL} (t _f)	90% AMP (V) 10% LOW V 1TLH (t _r)
POSITIVE PULSE	10% t _{TLH} (t _r)	90% t _{THL} (t _f) AMP (V) VM 10% LOW V

 $V_{\mbox{\it M}}$ = 1.55V for $\overline{\mbox{\it Bn}},\,V_{\mbox{\it M}}$ = 1.5V for all others. Input Pulse Definitions

Family	INPUT PULSE REQUIREMENTS											
FB+	Amplitude	Low V	Rep. Rate	t _W	t _{TLH}	t _{THL}						
A Port	3.0V	0.0V	1MHz	500ns	2.5ns	2.5ns						
B Port	2.0V	1.0V	1MHz	500ns	2.0ns	2.0ns						

DEFINITIONS:

R_L = Load Resistor; see AC CHARACTERISTICS for value.
C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 Termination resistance should be equal to Z_{OUT} of pulse generators.
 Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

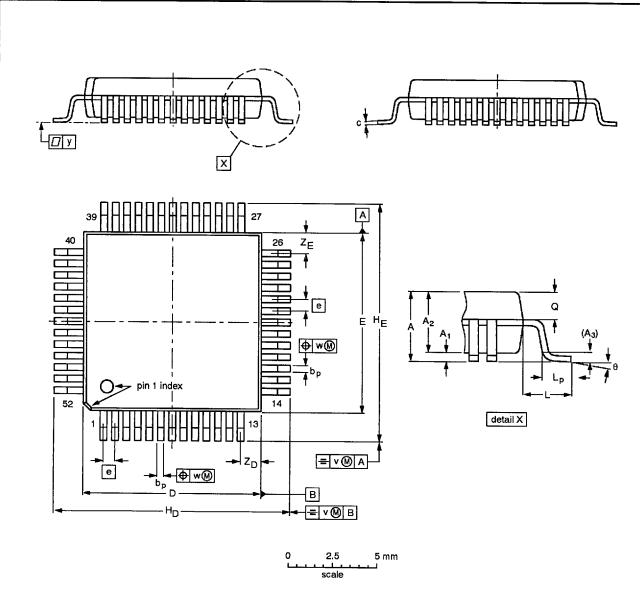
R_U = Pull up resistor; see AC CHARACTERISTICS for value.

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QFP52: plastic quad flat package; 52 leads (lead length 1.6 mm); body 10 x 10 x 2.0 mm

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DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	ь _р	C	D(4)	E ⁽¹⁾	e	H _D	HE	L	Lp	Q	v	w	у	Z _D ⁽¹⁾	Z _E ⁽¹⁾	θ
mm	2.45	0.45 0.25	2.10 1.95	0 25	0.38 0.22	0.23 0.13	10.1 9.9	10.1 9.9	0.65	13.45 12.95	13.45 12.95	1.60	0.95 0.65	1.05 0.90	0.20	0.12	0.10	1.24 0.95	1.24 0.95	7° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		EUROPEAN					
VERSION	IEC	JEDEC	EDEC EIAJ		PROJECTION	ISSUE DATE	
SOT379-1		MO-108				95-02-04	